



TO-92 Plastic-Encapsulate Transistors

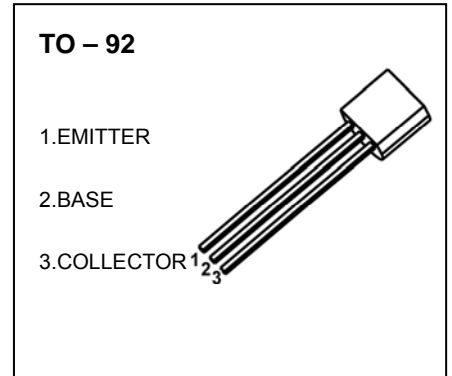
KSB564A TRANSISTOR (PNP)

FEATURES

- Complement to KSD471A
- Low $V_{CE(sat)}$

APPLICATION

- Audio Frequency Power Amplifier



MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-30	V
V_{CEO}	Collector-Emitter Voltage	-25	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-1	A
P_C	Collector Power Dissipation	800	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	156	$^{\circ}C/W$
T_j	Junction Temperature	150	$^{\circ}C$
T_{stg}	Storage Temperature	-55~+150	$^{\circ}C$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-0.1mA, I_E=0$	-30			V
Collector-emitter breakdown	$V_{(BR)CEO}$	$I_C=-10mA, I_B=0$	-25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-0.1mA, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-30V, I_E=0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5V, I_C=0$			-0.1	μA
DC current gain	h_{FE}	$V_{CE}=-1V, I_C=-0.1A$	70		400	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-1A, I_B=-0.1A$			-0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-1A, I_B=-0.1A$			-1.2	V
Collector output capacitance	C_{ob}	$V_{CB}=-6V, I_E=0, f=1MHz$		18		pF
Transition frequency	f_T	$V_{CE}=-6V, I_C=-10mA$		110		MHz

CLASSIFICATION OF h_{FE}

RANK	O	Y	G
RANGE	70-140	120-240	200-400